

1N3595



DO-35 Color Band Denotes Cathode

Small Signal Diode

Absolute Maximum Ratings*

 $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	150	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 4.0	A A
T _{stg}	Storage Temperature Range	-65 to +200	°C
TJ	Operating Junction Temperature	175	°C

 $^{{}^{\}bigstar} \text{These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.}$

Thermal Characteristics

Symbol	Parameter	Value	Units	
P _D	Power Dissipation	500	mW	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W	

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	$I_R = 100 \mu A$	150		V
V _F	Forward Voltage	$I_F = 1.0 \text{ mA}$ $I_F = 5.0 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 50 \text{ mA}$ $I_F = 100 \text{ mA}$ $I_F = 200 \text{ mA}$	0.52 0.60 0.65 0.75 0.79 0.83	0.68 0.75 0.80 0.88 0.92 1.00	V V V V
I _R	Reverse Current	\dot{V}_{R} = 125 V V_{R} = 30 V, T_{A} = 125°C V_{R} = 125 V, T_{A} = 125°C V_{R} = 125 V, T_{A} = 150°C		1 0.3 0.5 3	nA μA μA μA
C _T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		8	pF
t _{rr}	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 3.5 \text{ V},$ $R_L = 1.0 \text{ k}\Omega$		3	μs

¹⁾ These ratings are based on a maximum junction temperature of 200 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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Definition of Terms

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Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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1N3595

High Conductance Fast Diode

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Product status/pricing/packaging

Product	Product status	Pricing*	Inventory check & ordering	Package type	Leads	Package marking	Packing method
1N3595TR	Full Production	\$0.0408	Purchase	<u>DO-35</u>	2	\$Y 1N 35 95 CATHODE BAND	TAPE REEL
1N3595	Full Production	\$0.0408	Purchase	DO-35	2	\$Y 1N 35 95 STD CATHODE BAN	BULK

^{*} Fairchild 1,000 piece Budgetary Pricing

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